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Perovskite solar cells as a hot research topic show great urgency to control the interface. In this work, an insulating alkyl chain layer is self-assembled at the perovskite/hole transport material interface, which successfully exhibits dual function to block the electron recombination and resist the moisture at the same time. Improved solar energy conversion efficiency and stability of the device are both achieved.

Solid-state methylammonium lead halide perovskites solar cells are attracting much attention due to their ease of preparation, low cost and high efficiencies\(^1\)\(^-\)\(^4\). Up to now, the perovskite solar cell configuration becomes diverse and fundamentally much different\(^5\). For example, planar structured perovskite solar cells (without mesoporous TiO\(_2\) layer\(^6\)\(^-\)\(^8\)) meso-superstructured\(^9\),\(^10\) (with inert mesoporous Al\(_2\)O\(_3\), or ZrO\(_2\) scaffolds) and hole transport material free perovskite solar cells\(^11\). Though the structure is diverse, the interface lies in all these structures. In general, carriers are created in the perovskite absorber after the absorption of incident photons and travel through a transport pathway including the electron or hole transport layer, the electrodes and each interface in between\(^12\). Compared with other thin film solar cells, the perovskite solar cell is more prone to surface recombination due to imperfect crystal passivation and undesirable interfacial properties, resulting in fill factor (FF), open circuit voltage (\(V_{oc}\)) and short-circuit current (\(J_{sc}\)) losses\(^13\). Therefore, how to precisely manipulate the interface of perovskite solar cells to maximum the electron and hole separation/collection and minimum the electron recombination decides largely on the real cells’ performance.

More recently, there are efforts related to the interface engineering to change the interfacial photoelectrical properties, such as changing the work function of the electrode to a more suitable value\(^14\)\(^-\)\(^15\) or use more efficient electron collection layer\(^14\),\(^15\) and blocking layer\(^5\) for efficient charge separation and transportation. Supramolecular halogen bond passivation of surface defect states of perovskite also effectively reduces the interface recombination in the perovskite solar cells\(^16\).

Despite the evident success of interface engineering to improve the perovskite solar cell performance, the instability problem of perovskite material leaves an open issue for outdoor photovoltaic applications\(^17\). The instability stems from the CH\(_3\)NH\(_3\)PbI\(_3\) degrades in humid conditions. Replacement of CH\(_3\)NH\(_3\) group with more stable unit under moisture\(^18\) or using hydrophobic hole transport material\(^19\) can effectively alleviate the problem.

Here, a layer with long alkyl chains (dodecyl) is judiciously self-assembled on perovskite/TiO\(_2\) nanoparticle surface, which is the first time to use such a electron inactive molecular to perform bifunctionally in perovskite solar cells. On one hand, such alkyl chains function as an electrically insulating barrier, thereby reducing interfacial charge recombination losses in the perovskite solar cells, resulting in much enhanced FF, \(V_{oc}\) and \(J_{sc}\). On the other hand, the interface layer with alkyl chains effectively changes the hydrophilic nature of the perovskite surface to hydrophobic, thus endows the device more resistant of the moisture. It is believed that this bifunctional interface modification can be utilized in other structures of the perovskite solar cells.
Figure 1. Top: FT-IR plot of freshly prepared Cs$_{12}$silane in isopropanol. Bottom: ATR-FTIR spectra of perovskite CH$_3$NH$_2$PbI$_3$ film and the Cs$_{12}$silane (0.1M) modified perovskite film (Cs$_{12}$silane/CH$_3$NH$_2$PbI$_3$).

The attenuated total reflectance-Fourier transform infrared (ATR-FTIR) measurement (Figure 1) is used to check the chemical modification of Cs$_{12}$silane on the surface of perovskite. Pb-I bond is transparent in the IR region; only the organic groups are reflected in IR spectra. The -NH$_2$ vibration bands (3300-3150, 1535 and 1458cm$^{-1}$) 20, -CH$_3$ vibration at 1230cm$^{-1}$, -C-N character band at 1200-1025cm$^{-1}$ 21 can be found in CH$_3$NH$_2$PbI$_3$ spectrum. After interface modification of Cs$_{12}$silane, new bands clearly appeared in the contrast spectrum as the arrows indicated: γ-CH$_3$ strong stretching bands at 2920, 2850 cm$^{-1}$ and (CH$_2$)$_n$ (n>4) characteristic vibrations at 720 cm$^{-1}$, which are ascribed to the existence of the -C$_3$H$_7$$_{12}$ alkyl chains$^{22}$. The hydrogen bond of Si–OH⋯I cannot directly form a vibration peak in spectra, however, it will affect the Si–OH vibration. For freshly alcoholized Cs$_{12}$silane (top of Figure 1), it shows Si-O and Si-OCH$_3$ vibration at 1185-1035cm$^{-1}$ 23. When it is assembled on perovskite surface, the vibration band moves to lower frequency region 1135-1000cm$^{-1}$, indicating there is an interaction on Si-O. For the electrophilic property of Si–OH and the electron pairs on I, the formation of hydrogen bond Si–OH⋯I is thus occurred to influence the Si-O vibration to lower frequency region. Above changes in the ATR-FTIR spectra indicate the Cs$_{12}$silane is successfully assembled on the surface of perovskite through hydrogen bonding.

The modified perovskite is further checked by scanning electron microscope (SEM) to examine the surface morphology. As is shown in Figure 2, both of the samples are well crystallized in this experiment with large crystals presented, however, there still existed the holes which uncover the TiO$_2$ nanocrystalline layer. Compared with the original perovskite film, the Cs$_{12}$silane modified surface is more compact (inset of Figure 2) which is due to that the Cs$_{12}$silane might influence the crystallization process of the perovskite during baking. There is a phenomenon should be addressed that the morphology deformation is usually appeared in Cs$_{12}$silane modified samples during the scanning process. This is actually ascribed to the insulating property of the alkyl chain.

The quality of the as formed perovskite film is critical to the high performance of the device; otherwise, unsuccessful infiltration of perovskite with pin-hole results in low resistance shunting paths, causing electron recombination from the electron transport material (ETM) to the hole transport material (HTM), which is detrimental to the device performance$^{8,24-26}$. In SEM (Figure 2.a) of perovskite film, there are some holes distributed. After Cs$_{12}$silane modification, the surface of the perovskite appears more homogeneous as is shown in Figure 2.b. Furthermore, the long alkyl chains form a spacer between the perovskite and the HTM (spiro-MeOTAD), which may retard the electron recombination process especially the recombination from the uncovered TiO$_2$ in the working device, thus the improved performance can be achieved.

Current density versus voltage (J–V) characteristics of the perovskite photovoltaic cells were performed to examine the effects. A batch of more than 35 solar cells were tested and the efficiency distribution is indicated in Figure S1. Most of the cells with Cs$_{12}$silane modification exhibited superior performances than the original perovskite solar cells. For each Cs$_{12}$silane concentration, a representative cell is chose with the photovoltaic parameters shown in Table 1.

<table>
<thead>
<tr>
<th>Concentration</th>
<th>Jsc[mAcm$^{-2}$]</th>
<th>Voc[V]</th>
<th>FF</th>
<th>Eff[%]</th>
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<tr>
<td>0</td>
<td>18.75</td>
<td>0.908</td>
<td>0.555</td>
<td>9.88</td>
</tr>
<tr>
<td>0.05</td>
<td>20.03</td>
<td>0.929</td>
<td>0.666</td>
<td>12.96</td>
</tr>
<tr>
<td>0.1</td>
<td>20.23</td>
<td>0.959</td>
<td>0.677</td>
<td>13.74</td>
</tr>
<tr>
<td>0.15</td>
<td>19.12</td>
<td>0.942</td>
<td>0.609</td>
<td>11.47</td>
</tr>
<tr>
<td>0.2</td>
<td>19.58</td>
<td>0.962</td>
<td>0.555</td>
<td>10.89</td>
</tr>
</tbody>
</table>

The original perovskite solar cell exhibits Jsc of 18.75 mAcm$^{-2}$, Voc of 0.908V, FF of 0.555 and Eff of 9.88%. The original device performs ordinarily. By contrast, after the Cs$_{12}$silane modification, the Voc and FF show solid enhancement, thus the performance is largely improved. The optimum Cs$_{12}$silane modification (0.1M) results in 13.74% performance with Jsc of 20.23 mAcm$^{-2}$, Voc of 0.959V, FF of 0.677. The current density versus voltage (J-V) curves of these two samples are shown in Figure 3 (a). The increase of FF is due to the enhanced shunt resistance and the reduced series resistance of the cell$^{27}$. In this work, FF exhibits a great improvement from 0.555 of the original device to 0.677 of 0.1M Cs$_{12}$silane modified solar cell. The Cs$_{12}$silane with insulating alkyl chains provides spatial separation between electrons in the perovskite and holes in the solid state hole conductor, increasing the shunt resistance of the device, thus the recombination is retarded and the FF is largely improved.

Such insulate or blocking property of the Cs$_{12}$silane layer in the working cell is illustrated in Figure 3 (b).
The blocking effect of the alkyl chain can be also identified from the dark J-V curves shown in Figure 3 (a). The onset of dark current of C$_{12}$-silane modified device means high charge separation yields, which is ascribed to the reduced recombination. Too much C$_{12}$-silane content (0.2M) used might influence the hole transfer between the perovskite and the spiro-MeOTAD, which lead to the inferior Jsc compared with the lower C$_{12}$-silane content (Table 1).

The blocking effect of the alkyl chain can be also identified from the dark J-V curves shown in Figure 3 (a). The onset of dark current of C$_{12}$-silane modified device is largely moved to higher bias voltage, which means the extent of recombination is greatly suppressed. (Hysteresis property is shown in Figure S3.)

Electrochemistry impedance spectroscopy (EIS), which recently has been successfully introduced to perovskite solar cell system to monitor the interfacial changes, is checked for the two contrast samples. Two arcs are appeared in the Nyquist plots in Figure 4.a : high frequency arc (left part) is ascribed to the contact resistance at the HTM/Ag electrode; while the lower frequency one (right part) is associated with the recombination resistance ($R_{rec}$) and chemical capacitance of the system (equivalent circuit, Figure S2). The $R_{rec}$, which is the diameter of the middle frequency arc is related to the recombination of electrons in perovskite/TiO$_2$ with hole transport layer (HTM). It is clear that the $R_{rec}$ is much larger for the 0.1M C$_{12}$-silane modified device under dark at bias of 0.8V compared with the original device, which means that the charge recombination is blocked. It is consistent with the photovoltaic property of the devices. The electron lifetime $\tau$ can be derived from the formula $\tau = (2\pi f)^{-1}$, where $f$ is the character frequency. The 0.1M C$_{12}$-silane modified sample shows more prolonged electron lifetime of 6.13mS at 0.8V bias voltage under dark, compared with 2.43mS for the original perovskite solar cell.

Different bias voltages were applied for EIS measurement. The derived $R_{rec}$ and $\tau$ values plotted with the bias voltage is presented in Figure 4. b. The C$_{12}$-silane modified sample shows higher $R_{rec}$ and $\tau$ values under all the bias voltage applied, in contrast to the unmodified solar cell. The results strongly support that the insulating/blocking effect of the alkyl chains in C$_{12}$-silane interlayer, thus it prolongs the electron lifetime and facilitates the electron collection.

In fact, interface engineering to form an insulate layer to suppress the electron recombination is not new in dye sensitized solar cells. Here, the same function of the alkyl chains is also achieved in the perovskite solar cells. What is more, it is interesting to notice another phenomenon of the long alkyl chain layer: the contact angles of de-ionized water on the surfaces of C$_{12}$-silane modified and original perovskite films are of great difference.

The contact angle of the C$_{12}$-silane modified perovskite film is changed to 86.3°, nearly two times larger than 44.1° of the original film. It indicates the C$_{12}$-silane with hydrophobic alkyl chain effectively changes the hydrophilic property of the perovskite film surface. The modified sample is more hydrophobic than the original one. It is known that CH$_3$NH$_3$PbI$_3$ is extremely soluble in water and even in low humidity conditions, which bring instable problem to this device. Even the Li salt in the HTM is hydroscopic which will worsen the instability. Cover the hydrophilic perovskite surface with the hydrophobic chain might change the situation. By checking the XRD of the perovskite film and the device performance change with time, this assumption is verified.

Decomposition of CH$_3$NH$_3$PbI$_3$ in moisture will convert to PbI$_2$ phase. The XRD of perovskite film on glass with and without C$_{12}$-silane modification under a relative humidity level of 40% is presented in Figure 6. (a) and (b). The peaks at 14.06, 28.40, and 43.30° are respectively assigned to the (110), (220), and (330) planes of CH$_3$NH$_3$PbI$_3$. It is clear that new phase of PbI$_2$ is presented in original perovskite film after two days as the star indicated, and the intensity of this peak increases with the time. It indicates that the decomposition is deteriorated with time.

By contrast, the C$_{12}$-silane modified perovskite is more stable in the test environment. Such phenomenon is ascribed to the long alkyl chain layer that is resisted of water. The efficiency test results are shown in Figure 6. (c). The efficiency of the original device without the C$_{12}$-silane modification shows steady decrease of the Jsc and the efficiency; while the modified one is more stable with the prolonged time. The unsealed cell with C$_{12}$-silane modification shows increase of Voc and FF within the first 100h.
After 600h in ambient environment, the efficiency keeps 85% of its initial value with Jsc deteriorated.

Figure 6. The XRD plots of perovskite film (a) and 0.1M C12-silane modified perovskite (b) on glass under 40% relative humidity. The normalized efficiency change with time (c), the solar cells are unsealed and the humidity of ambient environment is no more than 45%.

Conclusions

In conclusion, by a simple dip coating method, an insulating and hydrophobic layer with long alkyl (dodecyl) chain is formed at the perovskite/HTM interface. On one hand, the insulating alkyl chains prohibit the electron back reaction from the TiO2/perovskite to HTM, thus effectively enhance the as fabricated solar cell performance with solid increased FF and Voc. Electrochemical characterizations also verify this effect. On the other hand, the hydrophobic alkyl chain layer make the surface of perovskite more resistive to moisture, which renders the device more stable when compared with the unmodified one under ambient environment. The performance of C12-silane modification is thus proved to be judicious and bifunctional. Furthermore, it is irrigative that other long alkyl chain silane (C8, C16 or C30) may be explored to further optimise the electron transport and the moisture resistant property of the perovskite solar cells.

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